2008 IEEE Nuclear Science Symposium Dresden, Germany, October 19–25, 2008

Aging Effects and Operational Experience with the CDF Run II Silicon Detector



Ulrich Husemann Deutsches Elektronen-Synchrotron on behalf of the CDF Collaboration





The CDF Detector at the Tevatron



Fermi National Accelerator Laboratory – Aerial View



[[]Fermilab Visual Media Service]

- Tevatron: proton-antiproton collider at $\sqrt{s} = 1.96$ TeV
- Tevatron Run II: 2001–2009 (2010?)
- Luminosity: 5 fb⁻¹ delivered (Oct '08)
- Two multi-purpose particle physics detectors: CDF & DØ



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- CDF II: standard HEP detector with excellent tracking (silicon detectors & large drift chamber)
- Broad physics program: Higgs & BSM physics searches, top & B physics, QCD, ...

- Tevatron: proton-antiproton collider at $\sqrt{s} = 1.96$ TeV
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Silicon Detectors at CDF II



- CDF silicon = three subdetectors:
 - Layer 00 (L00): impact parameter
 - SVX II: workhorse for silicon tracking/vertexing & triggering
 - Intermediate Silicon Layers (ISL): link track to Central Outer Tracker drift chamber
- 7–8 silicon layers (6 m²),
 722,432 channels on 5,456 chips







3





- Long 1.5 year commissioning period (2001/2002)
- Phase I: "no ladder left behind" (2002–2006)
 - Vigilant monitoring on all levels: bit errors, single event upsets, ...
 - Aggressive recovery of problematic modules → maximize number of working channels
- Phase II: automation (2006–now)
 - Most failure modes well known
 - Automate many routine recovery procedures → maximize data-taking efficiency with fewer people
 - Automation example: auto-recovery after lost communication with power supply trips → complex interaction with run control and DAQ







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Power supply aging:

- Problem: several LV lines showed drooping voltages of O(100) days
- Diagnosis: aging regulating capacitor, needs to be replaced
- Fix: repair all (>100) power supplies during long shutdown





Radiation-induced single event upsets:

 Corrupted micro-sequencer memory in collision hall DAQ boards ("FIBs")

5

Scaling with luminosity



Infrastructure: ISL Cooling Leak



- First symptoms: electronic valve failures (early 2007)
- Problem: ISL coolant (10% ethylene glycol in water) became acidic (pH ≈ 2 = vinegar) during 2006 shutdown
- Solution: coolant neutralized by drain and flush procedure and large de-ionizers, unfortunately too late...
- May 2007: leaks in heat affected zone around aluminum welds in ISL Portcard ring (alloy: 6061-AI)





ISL Cooling Leak: The Fix



- Repair during 2007 shutdown (1 month of work for 4–5 people)
- Challenge #1: radiation damage
 - Must keep Silicon cold (and dry)
 - Solution: set up plastic tent, use air dryer to keep dew point below –10°C at all times
- Challenge #2: Portcard ring inaccessible from outside
 - Inside detector, approx. 1 m away from COT face
 - Repair through cooling tubes using borescopes, catheters, syringes, ...
 - Cover holes with epoxy using 0.75 mm brass tube
- Result: all leaks fixed, stable running since October 2007 (with improved instrumentation)







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7



Radiation Damage





- Challenge: operate CDF silicon for 6–7 fb⁻¹ of integrated luminosity (designed for 2–3 fb⁻¹)
 - Radiation damage: change in effective number of charge carriers
 - Depletion voltage V_{dep} decreases until type inversion of sensor material, then increases → may hit technical limit
- Method: dedicated data-taking runs ("Signal Bias Scans")
 - Study collected charge of silicon hits from good tracks during colliding beams operation
 - V_{dep} from peak of ADC spectrum for different bias voltages
 - Consumes valuable beam time (but alternative "Noise Bias Scan" works only for double sided sensors before type inversion)





Layer 00

- Radii: 1.35 cm ("narrow" sensors),
 1.62 cm ("wide" sensors)
- "LHC style" sensors: single sided, p-in-n, orientation
 <100>, some sensors oxygenated
- Measured radiation dose: 2–3 × 10¹⁰ MIPs per cm² and pb⁻¹ [R. J. Tesarek et al., IEEE NSS 2003]
- Results with 4.5 fb⁻¹:
 - Type inversion observed in all sensors → very consistent
 - Oxygenated narrow sensors invert after standard narrows and wides
 - Fit to bias scan data after inversion: Layer 00 will outlast Run II





Radiation Damage: Results for Layer 0/1



10





Summary and Conclusions





- CDF Run II silicon detectors: Layer 00, SVX, ISL
- Many years of operational experience: asset for the LHC experiments
- Important lesson: don't forget about infrastructure (cooling, power supplies, etc.)
- Radiation damage after 5 fb⁻¹:
 - Inner layers: all modules well beyond type inversion
 - Silicon detectors will outlast Tevatron Run II